

4N39X, 4N40X
4N39, 4N40



PHOTON COUPLED ISOLATOR Ga As INFRARED EMITTING DIODE & LIGHT ACTIVATED SCR

APPROVALS

- UL recognised, File No. E91231

'X' SPECIFICATION APPROVALS

- VDE 0884 in 2 available lead forms : -
 - STD
 - G form

DESCRIPTION

The 4N39, 4N40 are optically coupled isolators consisting of infrared light emitting diode and a light activated silicon controlled rectifier in a standard 6pin dual in line plastic package.

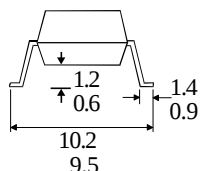
FEATURES

- Options :-
 - 10mm lead spread - add G after part no.
 - Surface mount - add SM after part no.
 - Tape&reel - add SMT&R after part no.
- High Isolation Voltage ($5.3kV_{RMS}$, $7.5kV_{PK}$)
- High Surge Anode Current (5.0 A)
- High Blocking Voltage (200V*¹, 400V*¹)
- Low Turn on Current (5mA typical)
- All electrical parameters 100% tested
- Custom electrical selections available

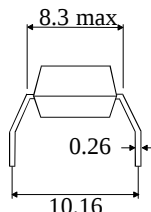
APPLICATIONS

- 10A, TTL compatible, Solid State Relay
- 25W Logic Indicator Lamp Driver
- 400V Symmetrical transistor coupler

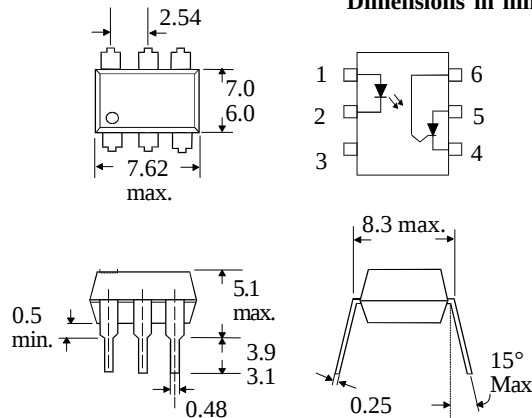
OPTION SM SURFACE MOUNT



OPTION G



Dimensions in mm



ABSOLUTE MAXIMUM RATINGS (25°C unless otherwise specified)

Storage Temperature _____ -55°C to + 150°C
Operating Temperature _____ -55°C to + 100°C
Lead Soldering Temperature
(1/16 inch (1.6mm) from case for 10 secs) 260°C

INPUT DIODE

Forward Current _____ 60mA
Forward Current (Peak)
(1μs pulse, 300pps) _____ 3A
Reverse Voltage _____ 6V
Power Dissipation _____ 100mW

DETECTOR

Peak Forward Voltage
4N39 _____ 200V*¹
4N40 _____ 400V*¹
Peak Reverse Gate Voltage _____ 6V
RMS On-state Current _____ 300mA
Peak On-state Current
(100μs, 1% duty cycle) _____ 10A
Surge Current (10ms) _____ 5A
Power Dissipation _____ 300mW

*1 IMPORTANT : A resistor must be connected between gate and cathode (pins 4 & 6) to prevent false firing ($R_{GK} < 56k\Omega$)

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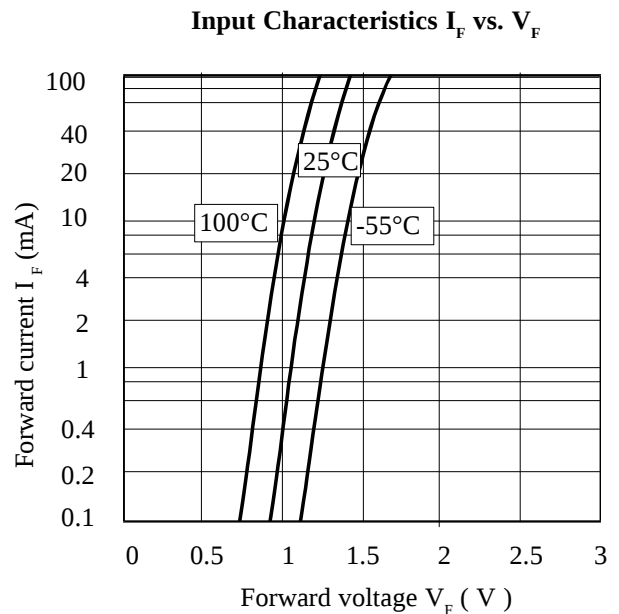
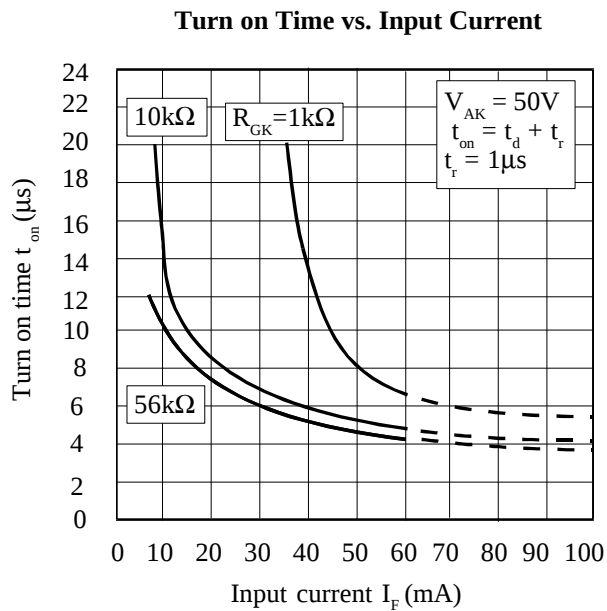
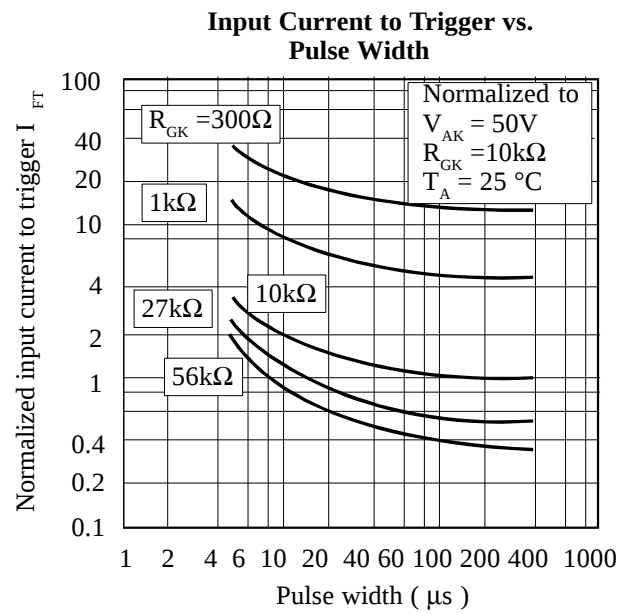
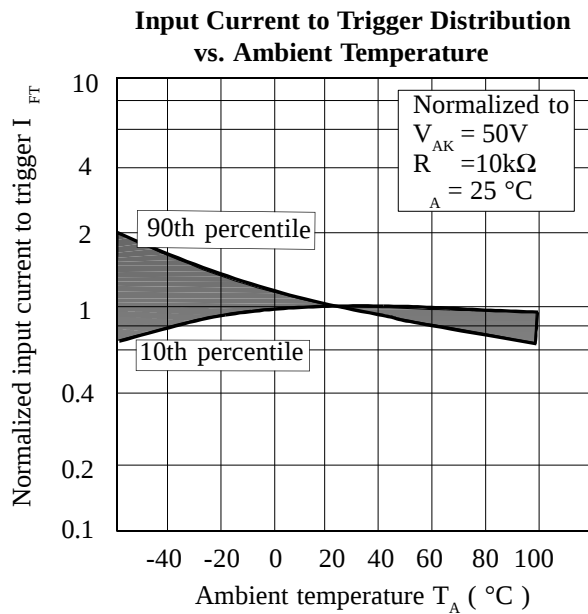
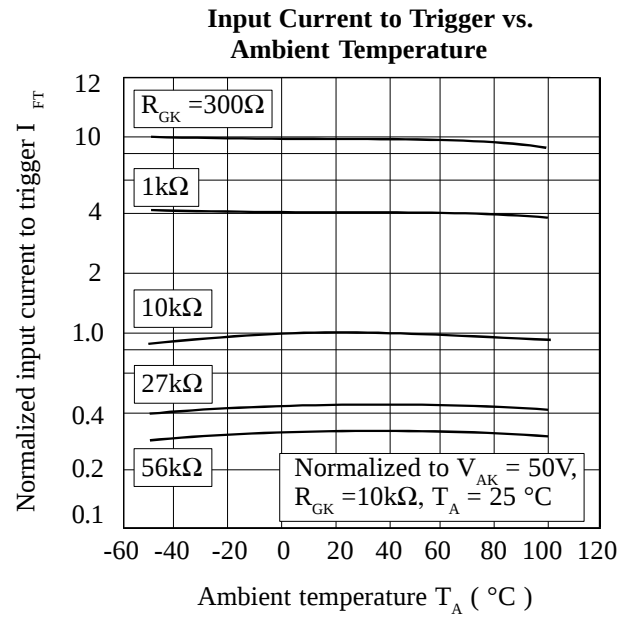
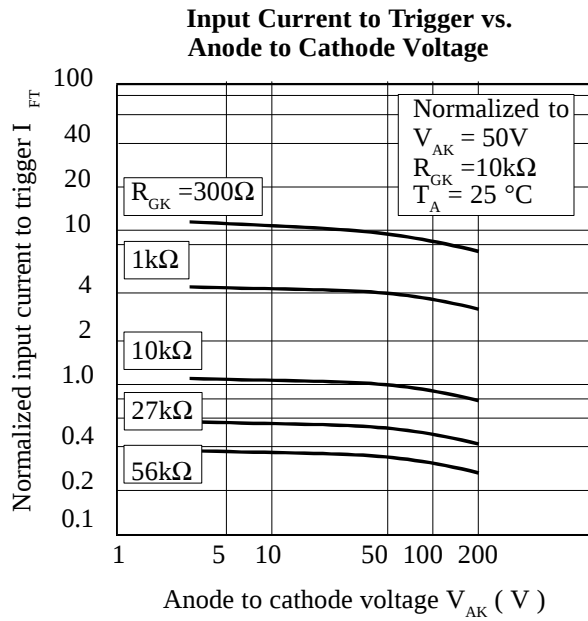
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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

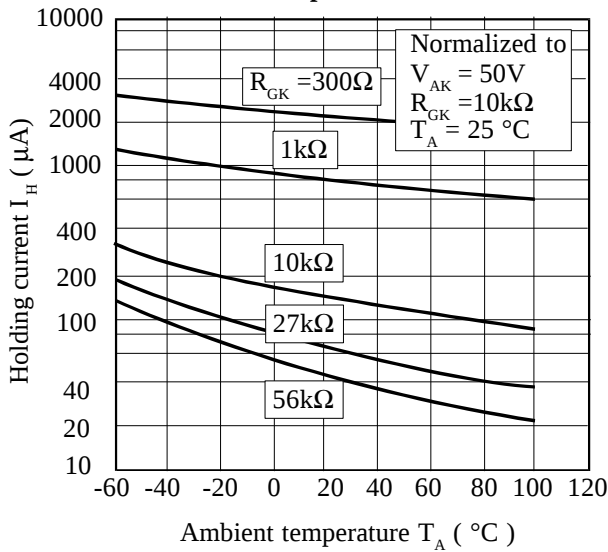
PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)	3	1.2	1.5	V	$I_F = 10\text{mA}$
	Reverse Voltage (V_R)				V	$I_R = 10\mu\text{A}$
Output (note 2)	Peak Off-state Voltage (V_{DM}) 4N39	200	1.1	1.3	V	$R_{GK}=10\text{k}\Omega$, $I_D = 50\mu\text{A}$, $T_A = 100^\circ\text{C}$
	4N40	400			V	$R_{GK}=10\text{k}\Omega$, $I_D = 150\mu\text{A}$, $T_A = 100^\circ\text{C}$
	Peak Reverse Voltage (V_{RM}) 4N39	200			V	$R_{GK}=10\text{k}\Omega$, $I_D = 50\mu\text{A}$, $T_A = 100^\circ\text{C}$
	4N40	400			V	$R_{GK}=10\text{k}\Omega$, $I_D = 150\mu\text{A}$, $T_A = 100^\circ\text{C}$
	On-state Voltage (V_{TM})				V	$I_{TM} = 300\text{mA}$
	Off-state Current (I_{DM}) 4N39			50	μA	$R_{GK}=10\text{k}\Omega$, $I_F = 0$, $V_{DM}=200\text{V}$, $T_A = 100^\circ\text{C}$
	4N40			150	μA	$R_{GK}=10\text{k}\Omega$, $I_F = 0$, $V_{DM}=400\text{V}$, $T_A = 100^\circ\text{C}$
	Reverse Current (I_R) 4N39			50	μA	$R_{GK}=10\text{k}\Omega$, $I_F = 0$, $V_{DM}=200\text{V}$, $T_A = 100^\circ\text{C}$
	4N40			150	μA	$R_{GK}=10\text{k}\Omega$, $I_F = 0$, $V_{DM}=400\text{V}$, $T_A = 100^\circ\text{C}$
	Holding Current (I_H)			1	mA	$R_{GK}=27\text{k}\Omega$, $V_{FX}=50\text{V}$
Coupled	Input Current to Trigger (I_{FT}) (note 2)			30	mA	$V_{AK}=50\text{V}$, $R_{GK}=10\text{k}\Omega$
				14	mA	$V_{AK}=100\text{V}$, $R_{GK}=27\text{k}\Omega$
	Turn on Time (t_{on})			50	μs	$R_{GK}=10\text{k}\Omega$, $I_F=30\text{mA}$, $V_{AK}=50\text{V}$, $R_L=200\Omega$
	Coupled dv/dt, Input to Output (dv/dt)	500			V/ μs	
	Input to Output Isolation Voltage V_{ISO}	5300 7500			V_{RMS} V_{PK}	See note 1 See note 1
	Input-output Isolation Resistance R_{ISO}	10^{11}			Ω	$V_{IO} = 500\text{V}$ (note 1)
	Input-output Capacitance C_f			2	pF	$V = 0$, $f = 1\text{MHz}$

Note 1 Measured with input leads shorted together and output leads shorted together.

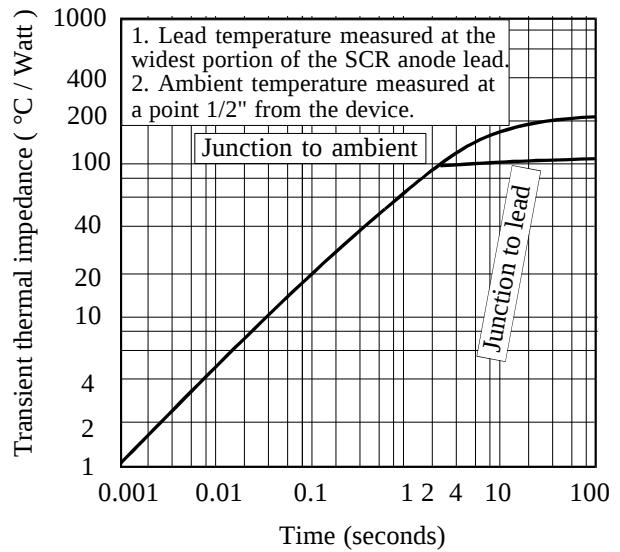
Note 2 Special Selections are available on request. Please consult the factory.



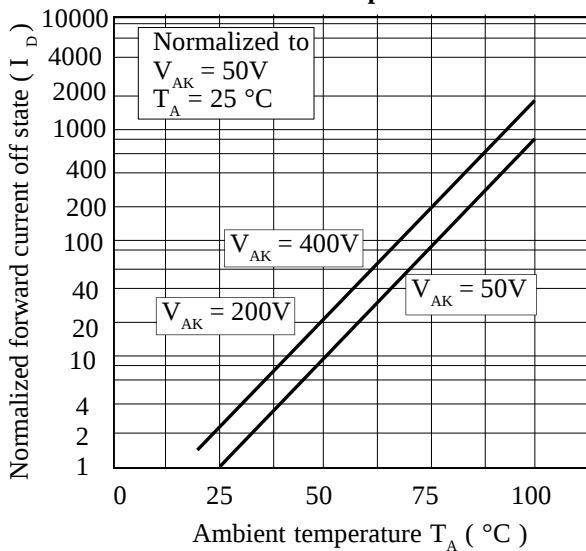
Holding Current vs. Ambient Temperature



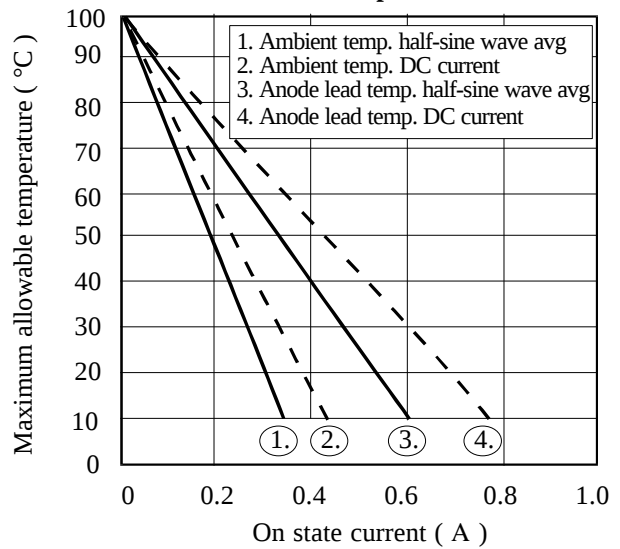
Maximum Transient Thermal Impedance



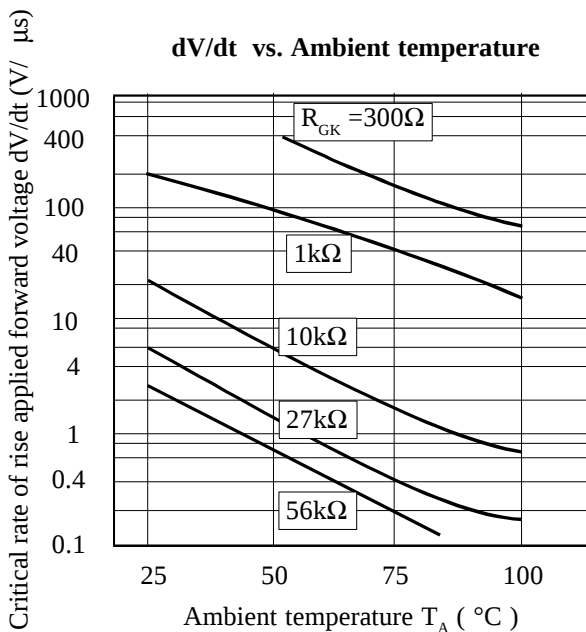
Off State Forward Current vs. Ambient Temperature



On State Current vs. Maximum Allowable Temperature



dV/dt vs. Ambient temperature



On State Characteristics

